



T-52-07

74BCT125

Quad Buffer with TRI-STATE® Outputs

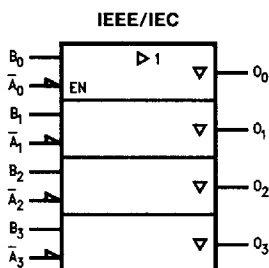
General Description

The 74BCT125 is a quad buffer with TRI-STATE outputs designed to be employed as a memory and address driver or bus-oriented transmitter/receiver. Each output is disabled by its own associated $\bar{A}_n$.

Features

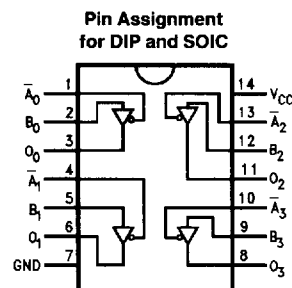
- TRI-STATE outputs drive bus lines or buffer memory address registers
- Low I_{CCZ} through BiCMOS techniques
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Guaranteed 2000V minimum ESD protection
- Guaranteed latchup protection
- Nondestructive hot insertion capability
- High impedance in power down (I_{ZZ} and V_{IO})

Logic Symbol



TL/F/10946-1

Connection Diagram



TL/F/10946-2

Pin Names	Description
$\bar{A}_n, B_n$	Inputs
O_n	Outputs

Function Table

Inputs		Output
$\bar{A}_n$	B_n	O
L	L	L
L	H	H
H	X	Z

H = High Voltage Level
L = LOW Voltage Level
Z = High impedance
X = Immaterial

9000-3488

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	
Plastic	-55°C to +150°C
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Voltage Applied to Any Output in the Disable or Power-Off State in the HIGH State	-0.5V to +5.5V -0.5V to V _{CC}
Current Applied to Output in LOW State (Max)	twice the rated I _{OL} (mA)
ESD Last Passing Voltage (Min)	2000V
DC Latchup Source Current	500 mA
Over Voltage Latchup	V _{CC} + 4.5V

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	0°C to +70°C
Supply Voltage	
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter	74BCT			Units	V _{CC}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	2.4 2.0			V	Min	I _{OH} = -3 mA I _{OH} = -15 mA
V _{OL}	Output LOW Voltage			0.55	V	Min	I _{OL} = 64 mA
I _{IH}	Input HIGH Current			5	μA	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test			7	μA	Max	V _{IN} = 7.0V
I _{IL}	Input LOW Current			-50	μA	Max	V _{IN} = 0.5V
I _{ozH}	Output Leakage Current			100 20	μA	0V-2.7V 2.7V-5.5V	V _{OUT} = 2.7V
I _{ozL}	Output Leakage Current			-20	μA	0V-5.5V	V _{OUT} = 0.5V
I _{oz}	Output Leakage Current			±100 ±20	μA	0V-2.7V 2.4V-0V	$\bar{A}_n$ = 0.8V, V _{OUT} = 0.5V or 2.7V (Power Up) $\bar{A}_n$ = 0.8V, V _{OUT} = 0.5V or 2.7V (Power Down)
I _{OS}	Output Short-Circuit Current	-100		-225	mA	Max	V _{OUT} = 0V
I _{CEx}	Output HIGH Leakage Current			50	μA	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	4.75			V	0.0	I _{ID} = 1.9 μA (All Other Pins Grounded)
I _{ZZ}	Bus Drainage Test			100	μA	0.0V	V _{OUT} = 5.25V
I _{CCH}	Power Supply Current		8	20	mA	Max	V _O = HIGH
I _{CCL}	Power Supply Current		18	30	mA	Max	V _O = LOW
I _{CCZ}	Power Supply Current		6	12	mA	Max	V _O = HIGH Z

AC Electrical Characteristics

T-52-07

Symbol	Parameter	74BCT			74BCT		Units
		$T_A = +25^{\circ}\text{C}$ $V_{CC} = +5.0\text{V}$ $C_L = 50\text{ pF}$			$T_A, V_{CC} = \text{Com}$ $C_L = 50\text{ pF}$		
		Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay	1.6 2.7	3.6 6.3	5.2 7.5	1.6 2.7	5.7 7.7	ns
t_{PZH} t_{PZL}	Output Enable Time	3.4 5.0	6.5 7.8	9.0 10.4	3.4 5.0	10.3 11.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time	3.0 2.8	5.4 6.0	7.4 7.9	3.0 2.8	8.6 8.6	ns
t_{OSHL} (Note 1)	Pin to Pin Skew HL Data to Output			0.6		0.75	ns
t_{OSLH} (Note 1)	Pin to Pin Skew LH Data to Output			0.4		0.5	ns
t_{OST} (Note 1)	Pin to Pin Skew LH/HL Data to Output			3.5		3.7	ns
t_{PV} (Note 2)	Device to Device Skew LH/HL Data to Output			3.8		4.0	ns

Extended AC Electrical Characteristics

Symbol	Parameter	74BCT		74BCT		74BCT		Units
		$T_A = \text{Com}$ $V_{CC} = \text{Com}$ $C_L = 50 \text{ pF}$ 4 Outputs Switching (Note 3)		$T_A = \text{Com}$ $V_{CC} = \text{Com}$ $C_L = 250 \text{ pF}$ 1 Output Switching (Note 4)		$T_A = \text{Com}$ $V_{CC} = \text{Com}$ $C_L = 250 \text{ pF}$ 4 Outputs Switching (Notes 3, 4)		
		Min	Max	Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay Data to Output	3.0 3.0	6.5 8.5	3.0 3.0	8.0 10.0	4.0 4.0	9.0 11.5	ns
t_{OSHL} (Note 1)	Pin to Pin Skew HL Data to Output		0.8		1.2		1.3	ns
t_{OSLH} (Note 1)	Pin to Pin Skew LH Data to Output		0.6		0.8		0.9	ns
t_{OST} (Note 1)	Pin to Pin Skew LH/HL Data to Output		3.8		4.4		4.8	ns
t_{PV} (Note 2)	Device to Device Skew LH/HL Data to Output		4.0		4.8		4.9	ns

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (t_{OSHL}), LOW to HIGH (t_{OSLH}), or any combination switching LOW to HIGH and/or HIGH to LOW (t_{OST}).

Note 2: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device.

Note 3: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all low-to-high, high-to-low, etc.).

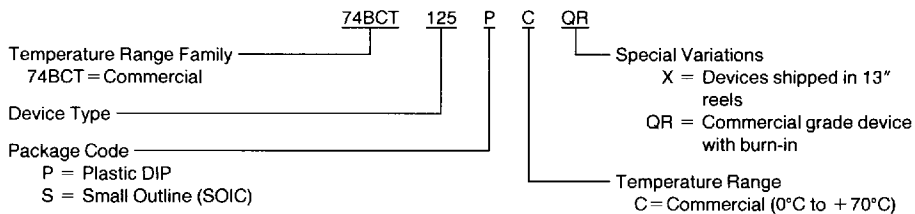
Note 4: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Capacitance**NATIONAL SEMICONDUCTOR (LOGIC)**

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Control Inputs	4.0	pF	$V_{CC} = 5.0V$
C_{OUT}	Output Pin Capacitance	9.0	pF	$V_{CC} = 5.0V$

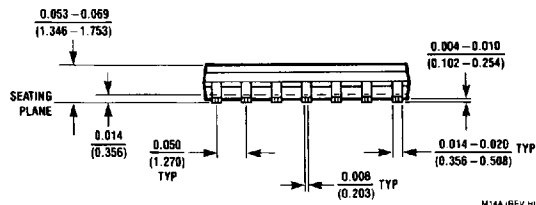
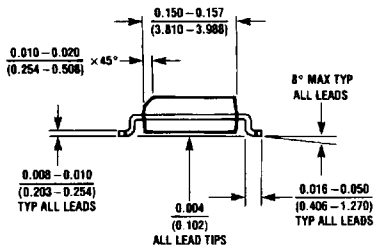
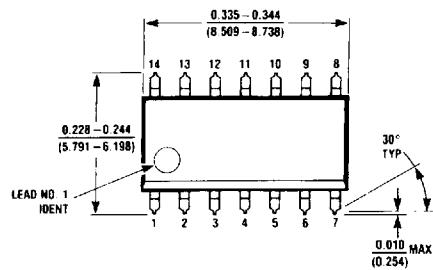
Ordering Information*T-52-07*

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



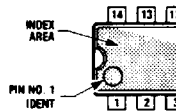
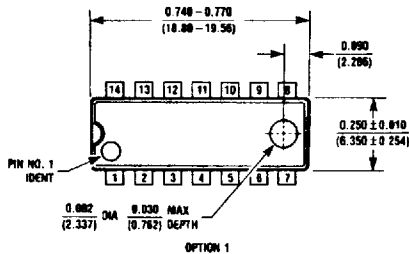
Physical Dimensions inches (millimeters)

NATIONAL SEMICOND (LOGIC)



14-Lead Small Outline Integrated Circuit (S)
NS Package Number M14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Plastic Dual-In-Line Package (P)
NS Package Number N14A

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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